

## Features

- Halogen Free. "Green" Device (Note 1)
- Moisture Sensitivity Level 1
- Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

## Maximum Ratings @ 25°C Unless Otherwise Specified

- Operating Junction Temperature Range: -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C

### NPN Transistor

Parameter	Symbol	Rating	Unit
Collector-Base Voltage	$V_{CBO}$	15	V
Collector-Emitter Voltage	$V_{CEO}$	12	V
Emitter-Base Voltage	$V_{EBO}$	6	V
Continuous Collector Current	$I_C$	500	mA
Power Dissipation	$P_D$	200	mW
Thermal Resistance Junction to Ambient	$R_{\theta JA}$	625	°C/W

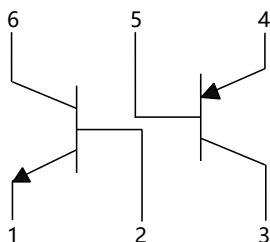
### PNP Transistor

Parameter	Symbol	Rating	Unit
Collector-Base Voltage	$V_{CBO}$	-15	V
Collector-Emitter Voltage	$V_{CEO}$	-12	V
Emitter-Base Voltage	$V_{EBO}$	-6	V
Continuous Collector Current	$I_C$	-500	mA
Power Dissipation	$P_D$	200	mW
Thermal Resistance Junction to Ambient	$R_{\theta JA}$	625	°C/W

Note: 1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

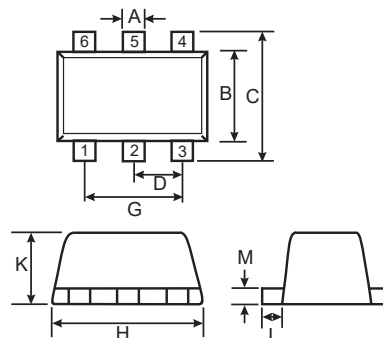
### Marking: Z7

### Internal Structure



# Dual Transistors

## SOT-563



DIM	DIMENSIONS				NOTE
	INCHES		MM		
	MIN	MAX	MIN	MAX	
A	0.006	0.011	0.15	0.30	
B	0.043	0.051	1.10	1.30	
C	0.059	0.067	1.50	1.70	
D	0.020		0.50		TYP.
G	0.035	0.043	0.90	1.10	
H	0.059	0.067	1.50	1.70	
K	0.022	0.026	0.55	0.65	
L	0.004	0.011	0.10	0.30	
M	0.004	0.007	0.10	0.18	

**Electrical Characteristics @  $T_A=25^\circ\text{C}$  Unless Otherwise Specified**
**NPN Transistor**

Parameter	Symbol	Min	Typ	Max	Units	Conditions
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	15			V	$I_C=100\mu\text{A}, I_E=0$
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	12			V	$I_C=1\text{mA}, I_B=0$
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	6			V	$I_E=100\mu\text{A}, I_C=0$
Collector Cutoff Current	$I_{CBO}$			100	nA	$V_{CB}=15\text{V}, I_E=0$
Emitter Cutoff Current	$I_{EBO}$			100	nA	$V_{EB}=5\text{V}, I_C=0$
DC Current Gain	$h_{FE}$	200				$V_{CE}=2\text{V}, I_C=10\text{mA}$
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$			0.22	V	$I_C=200\text{mA}, I_B=10\text{mA}$
Transition Frequency	$f_T$		420		MHz	$V_{CE}=5\text{V}, I_C=100\text{mA}, f=100\text{MHz}$
Output Capacitance	$C_{ob}$			6	pF	$V_{CB}=10\text{V}, I_E=0, f=1\text{MHz}$

**PNP Transistor**

Parameter	Symbol	Min	Typ	Max	Units	Conditions
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	-15			V	$I_C=-100\mu\text{A}, I_E=0$
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	-12			V	$I_C=-1\text{mA}, I_B=0$
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	-6			V	$I_E=-100\mu\text{A}, I_C=0$
Collector Cutoff Current	$I_{CBO}$			-100	nA	$V_{CB}=-15\text{V}, I_E=0$
Emitter Cutoff Current	$I_{EBO}$			-100	nA	$V_{EB}=-5\text{V}, I_C=0$
DC Current Gain	$h_{FE}$	200				$V_{CE}=-2\text{V}, I_C=-10\text{mA}$
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$			-0.22	V	$I_C=-200\text{mA}, I_B=-10\text{mA}$
Transition Frequency	$f_T$		280		MHz	$V_{CE}=-5\text{V}, I_C=-100\text{mA}, f=100\text{MHz}$
Output Capacitance	$C_{ob}$			10	pF	$V_{CB}=-10\text{V}, I_E=0, f=1\text{MHz}$

## Curve Characteristics(NPN)

Fig. 1 - Static Characteristics

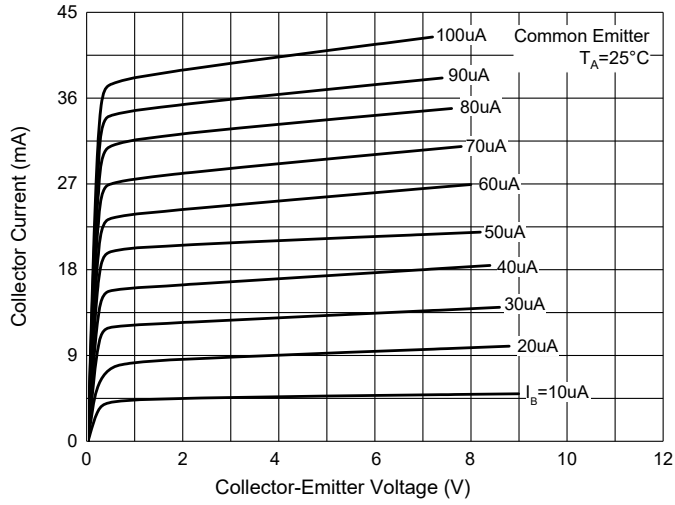


Fig. 2 - DC Current Gain Characteristics

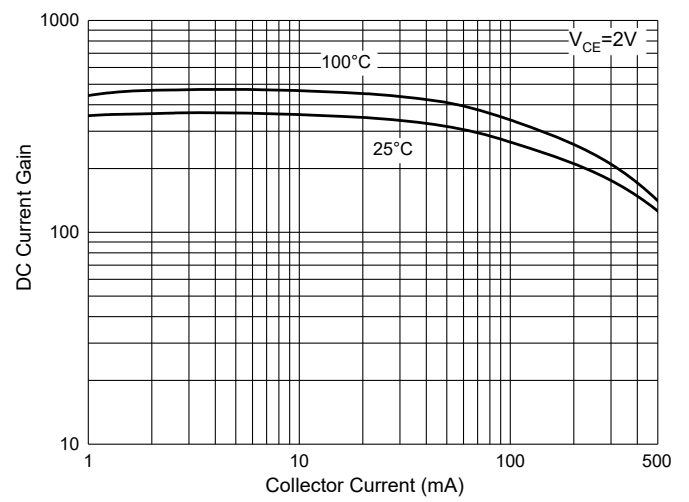


Fig. 3 - Collector-Emitter Saturation Voltage Characteristics

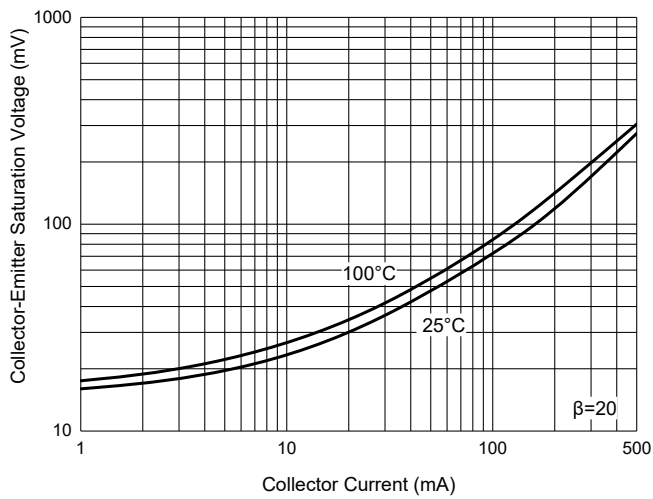
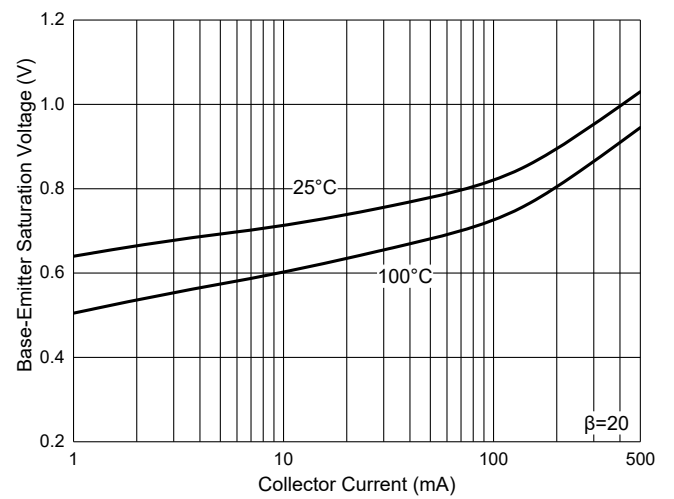


Fig. 4 - Base-Emitter Saturation Voltage Characteristics



## Curve Characteristics(PNP)

Fig. 5 - Static Characteristics

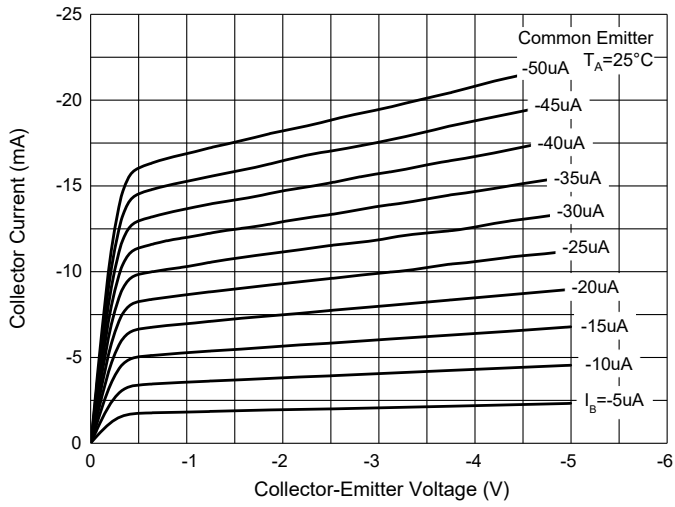


Fig. 6 - DC Current Gain Characteristics

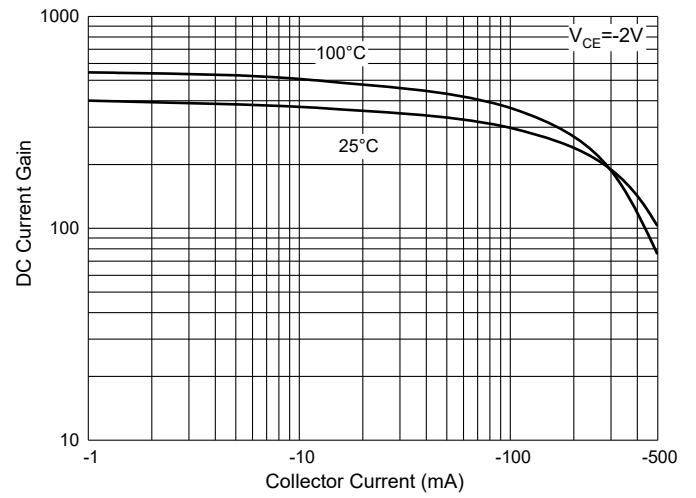


Fig. 7 - Collector-Emitter Saturation Voltage Characteristics

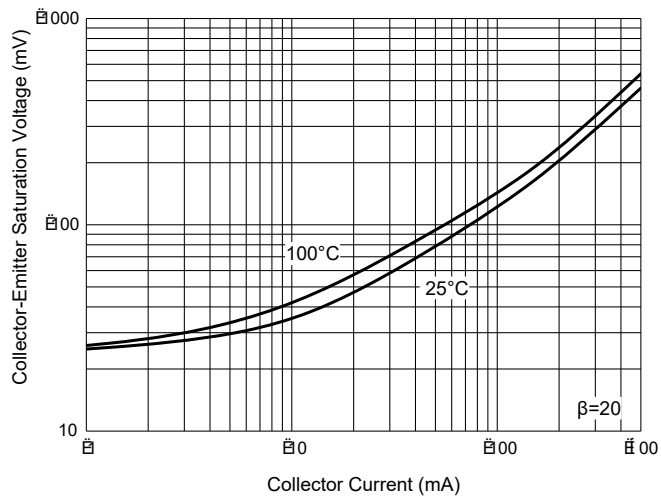
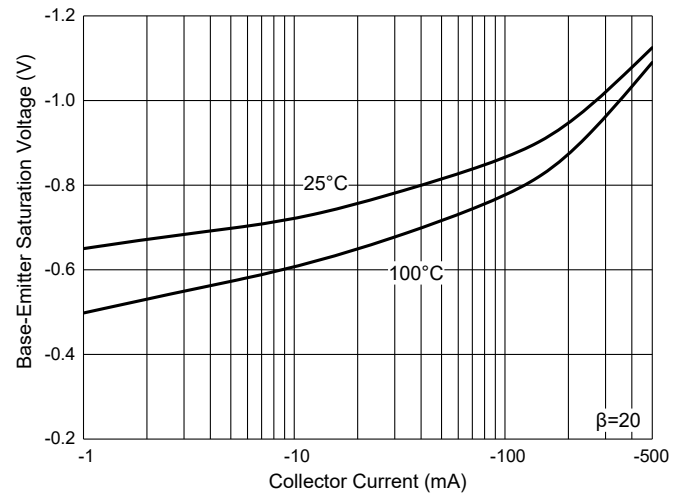


Fig. 8 - Base-Emitter Saturation Voltage Characteristics



## Ordering Information

Device	Packing
Part Number-TP	Tape&Reel: 3Kpcs/Reel

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